General Purpose Silicon Rectifiers



1N4001-G Thru. 1N4007-G

Voltage: 50 to 1000 V

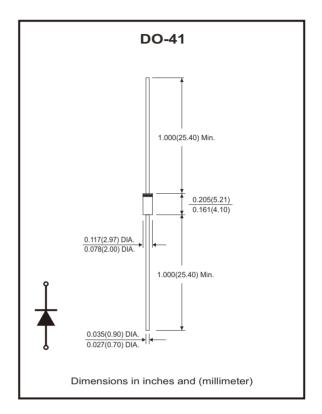
Current: 1.0 A RoHS Device

Features

- Low cost construction.
- Fast forward voltage drop.
- Low reverse leakage.
- High forward surge current capability.
- High soldering temperature guarantee: 260 °C/10 seconds, 0.375"(9.5mm) lead length at 5lbs(2.3kg) tension.

Mechanical data

- Case: Transfer molded plastic, DO-41
- Epoxy: UL 94V-0 rate flame retardant
- Polarity: Indicated by cathode band
- Lead: Plated axial lead, solderable per MIL-STD-750, method 2026
- Mounting position: Any
- Weight: 0.012ounce, 0.34 grams(approx.).



Electrical Characteristics (at TA=25°C unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load derate current by 20%.

Parameter		Symbol	1N4001 -G	1N4002 -G	1N4003 -G	1N4004 -G	1N4005 -G	1N4006 -G	1N4007 -G	Unit	
Maximum Repetitive Peak Reverse Voltage		Vrrm	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	V	
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	V	
Maximum Average Forward Rectified Current 0.375"(9.5mm) Lead Length @T _A =55°C		I _(AV)	1.0							Α	
Peak Forward Surge Current, 8.3mS single half sine-wave superimposed on rated load (JEDEC method)		Іғѕм	30							А	
Maximum Instantaneous Forward Voltage @1.0A		VF	1.1						V		
Maximum DC Reverse Current at Rated	T _A =25°C		5.0								
DC Blocking voltage per element	T _A =100°C	l _R				50				μA	
Typical Junction Capacitance (Note 1)		CJ	15					pF			
Typical Thermal Resistance (Note 2)		Reja	60						°C/W		
Operating Temperature Range		TJ	-55 ~ +150						°C		
Storage Ttemperature Range		Тѕтс	-55 ~ +150					°C			

NOTES:

- 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 2. Thermal Resistance from junction to ambient and junction to lead at 0.375"(9.5mm) lead length P.C.B mounted.

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Rating and Characteristic Curves (1N4001-G Thru. 1N4007-G)

Fig.1 - Typical Forward Current Derating Curve

1.2

(V)

(N)

1.0

0.8

0.6

0.2

Single phase Half wave, 60Hz Resistive or inductive load

0

25 50 75 100 125 150 175

Ambient Temperature, TA (°C)

Fig.3 - Typical Instantaneous Forward Characteristics

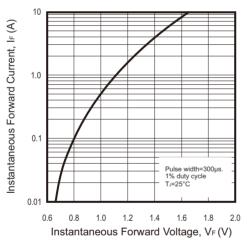


Fig.5 - Typical Junction Capacitance

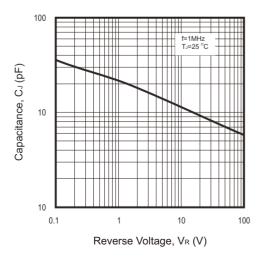


Fig.2 - Maximum. Non-Repetitive Peak Forward Surge Current

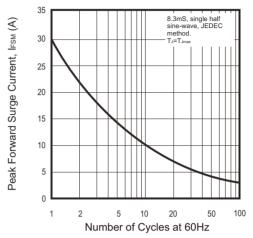
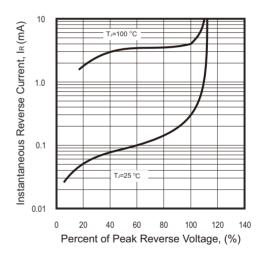
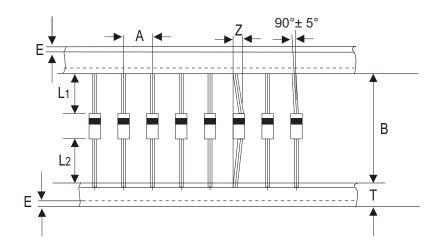


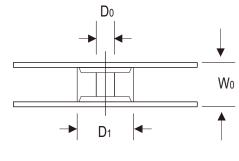
Fig.4 - Typical Reverse Characteristics

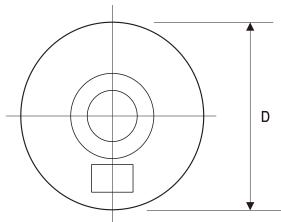


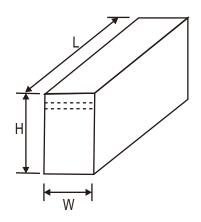


Taping Specification For Axial Lead Diodes









	SYMBOL	Α	В	Z	Т	E	L1-L2
DO-41	(mm)	5.00 ± 0.50	52.40 ± 1.50	1.60 (max)	6.00 ± 0.40	3.00 (max)	1.00 (max)
	(inch)	0.197 ± 0.020	2.063 ± 0.059	0.063 (max)	0.236 ± 0.016	0.118 (max)	0.039 (max)

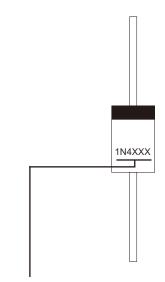
	SYMBOL	D1	D ₀	D	W ₀	L	W	Н
DO-41	(mm)	85.70 ± 0.30	16.60 ± 0.40	330.00	72.00 ± 3.00	260.00 ± 5.00	75.00 ± 5.00	150.00 ± 5.00
	(inch)	3.374 ± 0.012	0.654 ± 0.016	12.992	2.835 ± 0.118	10.236 ± 0.197	2.953 ± 0.197	5.906 ± 0.197

General Purpose Silicon Rectifiers



Marking Code

Part Number	Marking Code	Packaging
1N4001T-G	1N4001	REEL
1N4002T-G	1N4002	REEL
1N4003T-G	1N4003	REEL
1N4004T-G	1N4004	REEL
1N4005T-G	1N4005	REEL
1N4006T-G	1N4006	REEL
1N4007T-G	1N4007	REEL
1N4001A-G	1N4001	AMMO
1N4002A-G	1N4002	AMMO
1N4003A-G	1N4003	AMMO
1N4004A-G	1N4004	AMMO
1N4005A-G	1N4005	AMMO
1N4006A-G	1N4006	AMMO
1N4007A-G	1N4007	AMMO
1N4001B-G	1N4001	BULK
1N4002B-G	1N4002	BULK
1N4003B-G	1N4003	BULK
1N4004B-G	1N4004	BULK
1N4005B-G	1N4005	BULK
1N4006B-G	1N4006	BULK
1N4007B-G	1N4007	BULK



1N4XXX = Product type marking code

Note:

QW-BG013

1) Suffix code after part number to specify packaging item .

Packaging	Code
REEL PACK	Т
AMMO PACK	А
BULK PACK	В

Standard Packaging

	REEL PACK				
Case Type	REEL (pcs)	Reel Size (inch)			
DO-41	5,000	13			

	BULK PACK
Case Type	BOX (pcs)
DO-41	1,000

	AMMO PACK
Case Type	BOX (pcs)
DO-41	5,000